

## SURFACE MOUNT SWITCHING DIODE

#### **Features**

- High Reliability
- High Conductance
- For General Purpose Switching Applications

#### **Mechanical Data**

Case: MiniMELF, Glass

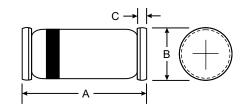
• Terminals: Solderable per MIL-STD-202,

Method 208

Marking: Cathode Band Only

Polarity: Cathode Band

Weight: 0.05 grams (approx.)



MiniMELF						
Dim	Min	Max				
Α	3.30	3.70				
В	1.30	1.60				
С	0.28	0.50				
All Dimensions in mm						

# Maximum Ratings @ T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	LL4454	Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	75	V	
Forward Continuous Current (Note 1)	I <sub>FM</sub>	300	mA	
Average Rectified Output Current (Note 1)	I <sub>O</sub>	150	mA	
Non-Repetitive Peak Forward Surge Current $\textcircled{0}$ t $\leq$ 1.0s $\textcircled{0}$ t = 1.0 $\mu$ s	I <sub>FSM</sub>	1.0 2.0	Α	
Power Dissipation (Note 1)	$P_d$	400	mW	
Thermal Resistance, Junction to Ambient Air (Note 1)	$R_{ hetaJA}$	300	K/W	
Operating and Storage Temperature Range	T <sub>j</sub> , T <sub>STG</sub>	-65 to +175	°C	

### **Electrical Characteristics** @ T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Maximum Forward Voltage Drop	$V_{FM}$	_	_	1.0	V	I <sub>F</sub> = 10mA
Maximum Peak Reverse Current	I <sub>RM</sub>	_	_	100	nA	V <sub>R</sub> = 50V
Junction Capacitance	Cj	_	4.0	_	pF	V <sub>R</sub> = 0V, f = 1.0MHz
Reverse Recovery Time	t <sub>rr</sub>		4.0	_	ns	$I_F = I_R = 10 \text{mA},$ $I_{rr} = 1.0 \times I_R, R_L = 100 \Omega$

Note: 1. Valid provided that electrodes are kept at ambient temperature.